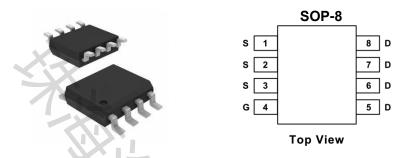


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SI9926CDY-T1-E3-HX P-Channel 30-V (D-S) MOSFET

PRODUCT SUMMARY					
VDS(V)	$RDS(on)(\Omega)$	ID (A)			
20	0.025 at VGS = 4.5 V	7.1			
20	0.035 at VGS = 2.5 V	6.0			



FEATURES

- TrenchFET® Power MOSFET
- 100 % R_g Tested

Applications

- Battery protection
- Load switch
- Power management

ABSOLUTE MAXIMUM RATINGS TA = 25 °C, unless otherwise noted					
Parameter	Symbol	Limit	Unit		
Drain- Source Voltage	VDS	20	V		
Gate- Source Voltage	Vgs	± 12			
Continuous Drain Current (T _J = 150 °C)a	TA = 25 °C	ID	7.1		
	TA = 70 °C		5.7		
Pulsed Drain Current (10 μs Pulse Width)		IDM	40	Α	
Continuous Source Current (Diode Conduction)	Is	1.7			
Maximum Power Dissipationa	TA = 25 °C	PD	2	W	
	TA = 70 °C		1.3		
Operating Junction and Storage Temperature R	ange	TJ , Tstg	- 55 to 150	°C	

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THERMAL RESISTANCE RATINGS					
Parameter	Symbol	Limit	Unit		
Maximum Junction- to- Ambienta	RthJA	62.5	°C/W		

Notes:

Surface Mounted on FR4 board, t ≤ 10 s.

SPECIFICATIONS TJ = 25 °C, unless otherwise noted						
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Static						
Gate Threshold Voltage	VGS(th)	VDS= VGS , ID = 250 μA	0.6		1.5	V
Gate- Body Leakage	Igss	VDS= 0 V, VGS = ± 12 V			± 100	nA
Zero Gate Voltage Drain Current	IDSS	V _{DS} = 20 V, V _{GS} = 0 V			1	μΑ
		V _{DS} = 20 V, V _{GS} = 0 V, T _J = 55 °C			5	
On-State Drain Currenta	ID(on)	V _{DS} ≥ 5 V, V _{GS} = 4.5 V	20			Α
Drain- Source On- State Resistancea	RDS(on)	V _G S = 4.5 V, I _D = 7.1 A		0.019	0.025	Ω
		VGS = 2.5 V, ID = 6.0 A		0.026	0.035	
Forward Transconductancea	gfs	V _{DS} = 10 V, I _D = 7.1 A		27		S
Diode Forward Voltagea	VsD	Is = 1.7 A, V _{GS} = 0 V			1.2	V
Dynamicb		< >>				
Total Gate Charge	Qg	Vps = 10 V.		9.5		
Gate- Source Charge	Qgs	VGS = 4.5 V,	, [1.5		nC
Gate- Drain Charge	Qgd	ID = 7.1 A		2.5		
Gate Resistance	Rg	f= 1MHz		1.6	2.7	Ω
Turn-On Delay Time	td(on)	V _{DD} = 10 V.		10		
Rise Time	tr	RL = 10 Ω		15		
Turn-Off Delay Time	td(off)	ID ≅1 A, VGEN = 4.5 V,		38		ns
Fall Time	tf	R _g = 10 Ω		25		
Source-Drain Reverse Recovery Time	trr	IF = 1.7 A, dI/dt = 100 A/μs		26		

- a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

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TYPICAL CHARACTERISTICS 25°C, unless otherwise noted

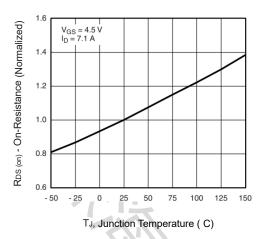
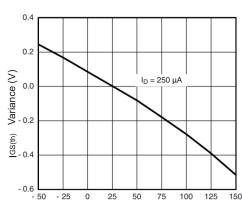
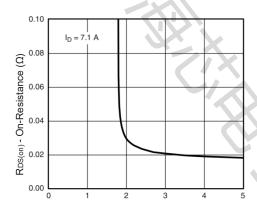


Fig 1. On-Resistance vs. Junction Temperature



TJ, Temperature (C)

Fig 2. Threshold Voltage



V_{GS} - Gate-to-Source Voltage (V) Fig 3. On-Resistance

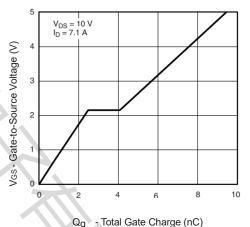
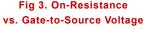


Fig 4. Gate Charge



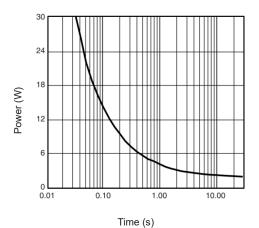
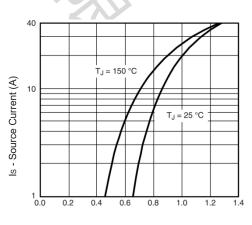


Fig 5. Single Pulse Power



V_{SD} - Source-to-Drain Voltage (V)

Fig 6. Source-Drain Diode Forward Voltage

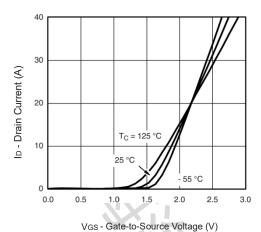
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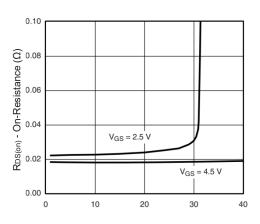


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TYPICAL CHARACTERISTICS 25°C, unless otherwise noted

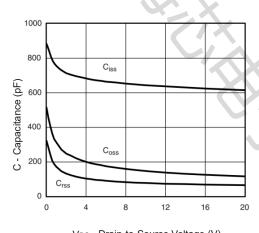




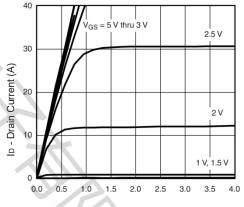
ID - Drain Current (A)

Fig 7. Transfer Characteristics

Fig 8. On-Resistance vs. Drain Current

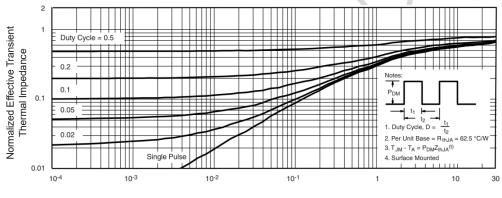


V_{DS} - Drain-to-Source Voltage (V) Fig 9. Capacitance



V_{DS} - Drain-to-Source Voltage (V)

Fig 10. Output Characteristics



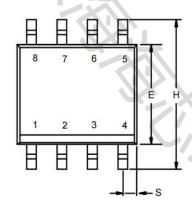
Square Wave Pulse Duration (s)

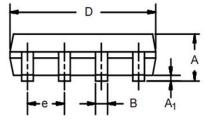
Fig 11. Normalized Thermal Transient Impedance, Junction-to-Ambient

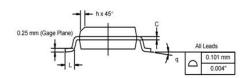
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SOP-8 Package Outline

Dimensions are shown in millimeters (inches)







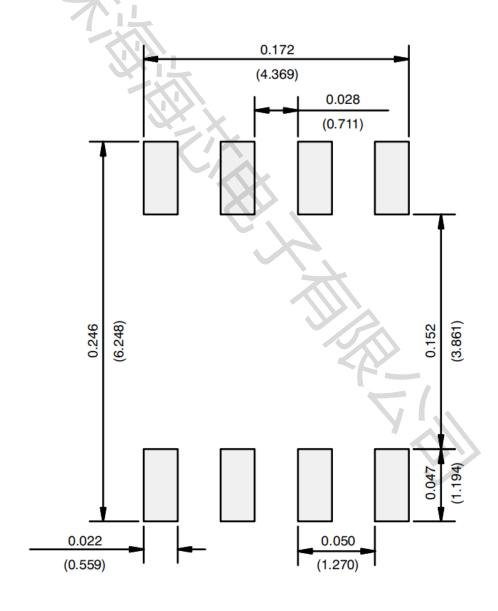
	MILLIN	IETERS	INCHE	S	
DIM	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A1	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
E	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	
S	0.44	0.64	0.018	0.026	

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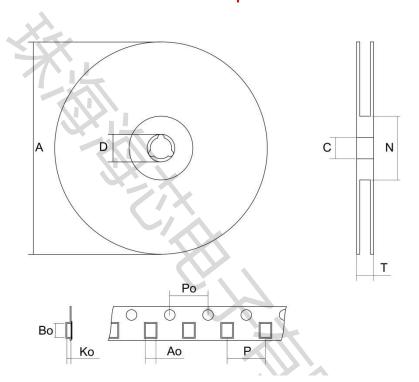
RECOMMENDED MINIMUM PADS FOR SOP-8



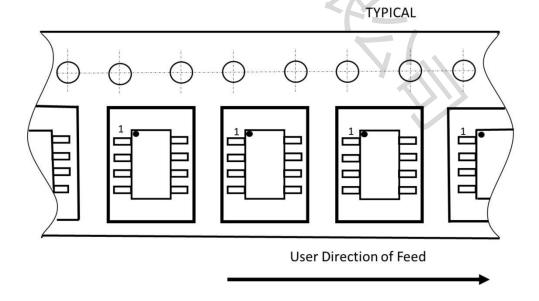
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SOP-8 packing information

SOP-8 tape and reel



Tape orientation



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